

October 2009

# HMHAA280, HMHA2801 Series, HMHA281 Half Pitch Mini-Flat Package 4-Pin Optocouplers

### **Features**

- Compact 4-pin package (2.4mm maximum standoff height)
- Half pitch leads for optimum board space savings

Current Transfer Ratio in selected groups
 HMHA2801: 80–600%
 HMHA2801B: 50–150%
 HMHA2801B

HMHA281: 50-600%

HMHA2801A: 80-160% HMHA2801C: 50-100% HMHAA280: 50-600%

- Available in tape and reel quantities of 2500
- CSA (File #1201524), UL (File #E90700) and VDE (File #136480) certified

### **Applications**

### **HMHAA280**

- AC line monitor
- Unknown polarity DC sensor
- Telephone line receiver

#### HMHA281, HMHA2801 Series

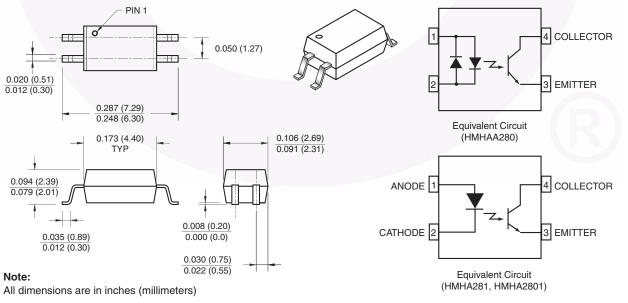
- Digital logic inputs
- Microprocessor inputs
- Power supply monitor
- Twisted pair line receiver
- Telephone line receiver

### Description

The HMHA281, HMHA2801 Series consists of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a compact 4-pin mini-flat package. The lead pitch is 1.27mm.

The HMHAA280 series consists of two gallium arsenide infrared emitting diodes, connected in inverse parallel, driving a single silicon phototransistor in a compact 4-pin mini-flat package. The lead pitch is 1.27mm.

### **Package Dimensions**



# **Absolute Maximum Ratings** ( $T_A = 25^{\circ}C$ unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Units	
TOTAL PACKAGE				
T <sub>STG</sub>	Storage Temperature	-55 to +125	°C	
T <sub>OPR</sub>	Operating Temperature	-55 to +100	°C	
EMITTER				
I <sub>F (avg)</sub>	Continuous Forward Current	50	mA	
I <sub>F (pk)</sub>	Peak Forward Current (1µs pulse, 300pps.)	1	А	
V <sub>R</sub>	Reverse Input Voltage (HMHA)	6	V	
P <sub>D</sub>	Power Dissipation	60	mW	
	Derate linearly (above 25°C)	0.6	mW/°C	
DETECTOR				
	Continuous Collector Current	50	mA	
P <sub>D</sub>	Power Dissipation	150	mW	
	Derate linearly (above 25°C)	1.5	mW/°C	
$V_{CEO}$	Collector-Emitter Voltage	80	V	
V <sub>ECO</sub>	Emitter-Collector Voltage	7	V	

### **Electrical Characteristics** (T<sub>A</sub> = 25°C)

Symbol	Parameter	Test Conditions	Device	Min.	Тур.*	Max.	Unit
	INDIVIDUAL COMPONENT CHARACTERISTICS						
Emitter							
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 10mA	HMHA281	1.0		1.3	V
			HMHA2801				/
			HMHA2801A	1.0		1.3	
			HMHA2801B				
		I <sub>F</sub> = 20mA	HMHA2801C			1.4	
		$I_F = \pm 5 \text{mA}$	HMHAA280			1.4	
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 5V	All			5	μΑ
Detector	Detector						
BV <sub>CEO</sub>	Breakdown Voltage Collector to Emitter	$I_C = 0.5 \text{mA}, I_F = 0$	All	80			V
BV <sub>ECO</sub>	Emitter to Collector	$I_E = 100 \mu A, I_F = 0$	All	7			
I <sub>CEO</sub>	Collector Dark Current	$V_{CE} = 80V, I_F = 0$	All			100	nA
C <sub>CE</sub>	Capacitance	$V_{CE} = 0V, f = 1MHz$	All		10		pF

# **Electrical Characteristics** ( $T_A = 25^{\circ}C$ ) (Continued)

Symbol	Characteristic	Test Conditions	Device	Min.	Тур.*	Max.	Unit
TRANSFER CHARACTERISTICS							
CTR	DC Current Transfer Ratio	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	HMHAA280	50		600	%
		$I_F = 5mA, V_{CE} = 5V$	HMHA281	50		600	
			HMHA2801	80		600	
			HMHA2801A	80		160	
			HMHA2801B	50		150	
		$I_F = 1$ mA, $V_{CE} = 5$ V	HMHA2801C	50		100	
	CTR Symmetry	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	HMHAA280	0.33		3.0	
V <sub>CE (SAT)</sub>	Saturation Voltage	$I_F = \pm 8mA, I_C = 2.4mA$	HMHAA280			0.4	V
		I <sub>F</sub> = 8mA, I <sub>C</sub> = 2.4mA	HMHA281			0.4	
		I <sub>F</sub> = 10mA, I <sub>C</sub> = 2mA	HMHA2801			0.3	
			HMHA2801A			0.3	
			HMHA2801B				
		I <sub>F</sub> = 20mA, I <sub>C</sub> = 1mA)	HMHA2801C			0.2	
t <sub>r</sub>	Rise Time (Non-Saturated)	$I_C = 2mA$ , $V_{CE} = 5V$ , $R_L = 100\Omega$	All except for HMHA2801C		3		μs
		$I_C = 2mA$ , $V_{CE} = 2V$ , $R_L = 1 \text{ K}\Omega$	HMHA2801C			9	
t <sub>f</sub> Fall Time (Non-Satura	Fall Time (Non-Saturated)	$I_C = 2mA$ , $V_{CE} = 5V$ , $R_L = 100\Omega$	All except for HMHA2801C		3		
		$I_C = 2mA$ , $V_{CE} = 2V$ , $R_L = 1K\Omega$	HMHA2801C			9	
		ISOLATION CHARACT	ERISTICS				
V <sub>ISO</sub>	Steady State Isolation Voltage	1 Minute	All	2500			VRMS

<sup>\*</sup>All typicals at  $T_A = 25^{\circ}C$ 

### **Typical Performance Characteristics**

Fig. 1 Forward Current vs. Forward Voltage

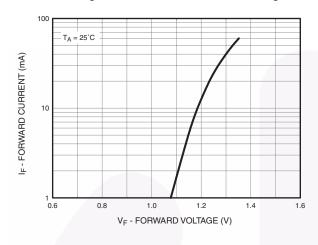


Fig. 2 Collector Current vs. Forward Current

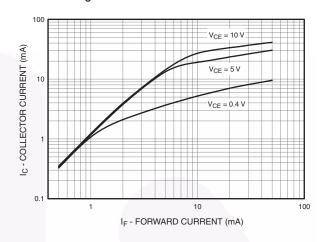


Fig. 3 Current Transfer Ratio vs. Forward Current

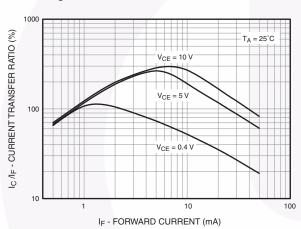


Fig. 4 Normalized CTR vs. Temperature

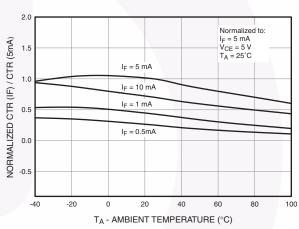
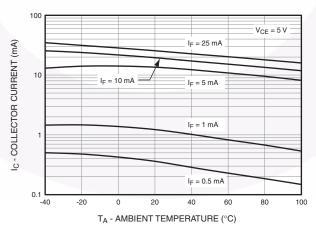


Fig. 5 Collector Current vs. Temperature



### **Typical Performance Characteristics** (Continued)

Fig. 6 Collector Current vs. Collector-Emitter Voltage

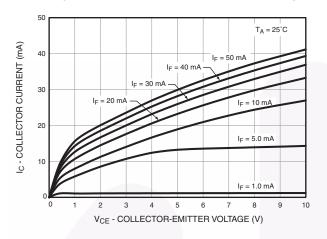


Fig. 7 Collector Current vs. Collector-Emitter Voltage

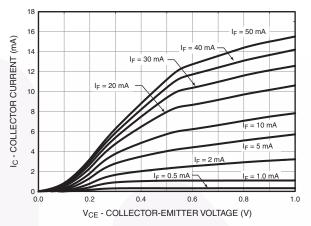
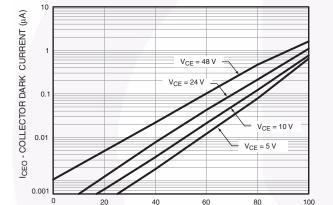


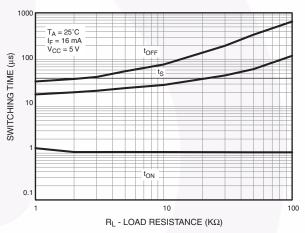
Fig. 8 Collector Dark Current vs. Temperature





T<sub>A</sub> - AMBIENT TEMPERATURE (°C)

Fig. 9 Switching Time vs. Load Resistance



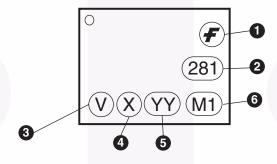
VCE(SAT) - COLLECTOR-EMITTER SATURATION VOLTAGE (V)

Fig. 10 Collector-Emitter Saturation Voltage vs. Temperature 0.30 I<sub>F</sub> = 5 mA 0.28 0.26 0.24 0.22 0.16 0.14 0.12 20 40 100 TA - AMBIENT TEMPERATURE (°C)

# **Ordering Information**

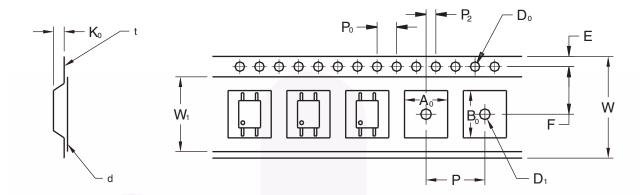
Option	Description	
V	VDE Approved	
R2	Tape and Reel (2500 units)	
R2V	Tape and Reel (2500 units) and VDE Approved	

# **Marking Information**



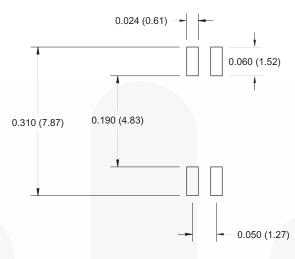
Definiti	ons
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

## **Tape and Reel Dimensions**

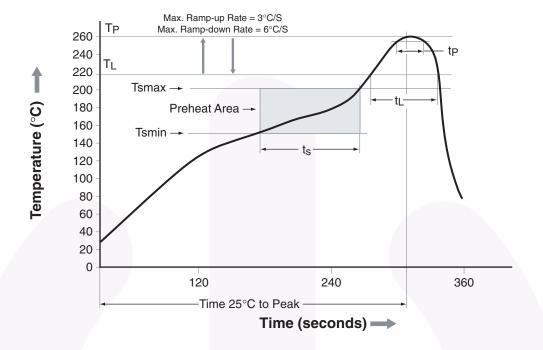


		2.54 Pitch
Description	Symbol	Dimensions
Tape Width	W	12.00±0.4
Tape Thickness	t	0.35±0.02
Sprocket Hole Pitch	P <sub>0</sub>	4.00±0.20
Sprocket Hole Dia.	D <sub>0</sub>	1.55±0.20
Sprocket Hole Location	E	1.75±0.20
Pocket Location	F	5.50±0.20
	P <sub>2</sub>	2.00±0.20
Pocket Pitch	Р	8.00±0.20
Pocket Dimension	A <sub>0</sub>	4.75±0.20
	B <sub>0</sub>	7.30±0.20
	K <sub>0</sub>	2.30±0.20
Pocket Hole Dia.	D <sub>1</sub>	1.55±0.20
Cover Tape Width	W <sub>1</sub>	9.20
Cover Tape Thickness	d	0.065±0.02
Max. Component Rotation or Tilt		20° max
Devices Per Reel		2500
Reel Diameter		330 mm (13")

# **Footprint Drawing for PCB Layout**



### **Reflow Profile**



Profile Freature	Pb-Free Assembly Profile		
Temperature Min. (Tsmin)	150°C		
Temperature Max. (Tsmax)	200°C		
Time (t <sub>S</sub> ) from (Tsmin to Tsmax)	60-120 seconds		
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.		
Liquidous Temperature (T <sub>L</sub> )	217°C		
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60-150 seconds		
Peak Body Package Temperature	260°C +0°C / -5°C		
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds		
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max.		
Time 25°C to Peak Temperature	8 minutes max.		

This reflow profile applies only to all HMHAXXXX devices with datecode marks starting from "0938" going forward. All preceding datecodes utilize a peak reflow temperature: 230°C (package surface temperature) for 30 seconds.





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Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

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